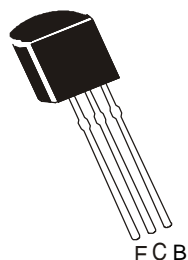


NPN SILICON EPITAXIAL TRANSISTOR

CSD1616
TO-92
BCE



Audio Frequency Power Amplifier And Medium Speed Switching Complementary CSB1116/1116A

ABSOLUTE MAXIMUM RATINGS(Ta=25deg C)

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector -Base Voltage	VCBO	60	V
Collector -Emitter Voltage	VCEO	50	V
Emitter Base Voltage	VEBO	6.0	V
Collector Current (DC)	IC	1.0	A
Collector Current (Pulse)	IC*	2.0	A
Collector Dissipation	PC	0.75	W
Operating And Storage Junction Temperature Range	Tj, Tstg	-55 to +150	deg C

*PW=10ms, duty Cycle=50%

ELECTRICAL CHARACTERISTICS (Ta=25 deg C Unless Specified)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector Cut off Current	ICBO	VCB=60V, IE=0	-	-	100	nA
Emitter Cut off Current	IEBO	VEB=6V, IC=0	-	-	100	nA
DC Current Gain	hFE(1) *	IC=100mA, VCE=2V	135	-	600	
	hFE(2) *	IC=1A, VCE=2V	81	-	-	
Base Emitter On Voltage	VBE(on)*	VCE=2V, IC=50mA	0.60	-	0.70	V
Collector Emitter Saturation Voltage	VCE(Sat)*	IC=1A, IB=50mA	-	-	0.30	V
Base Emitter Saturation Voltage	VBE(Sat)*	IC=1A, IB=50mA	-	-	1.2	V
Dynamic Characteristics						
Transition Frequency	ft	VCE=2V, IC=100mA,	100	-	-	MHz
Collector Output Capacitance	Cob	VCB=10V, IE=0	-	19	-	pF
		f=1MHz				

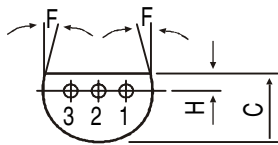
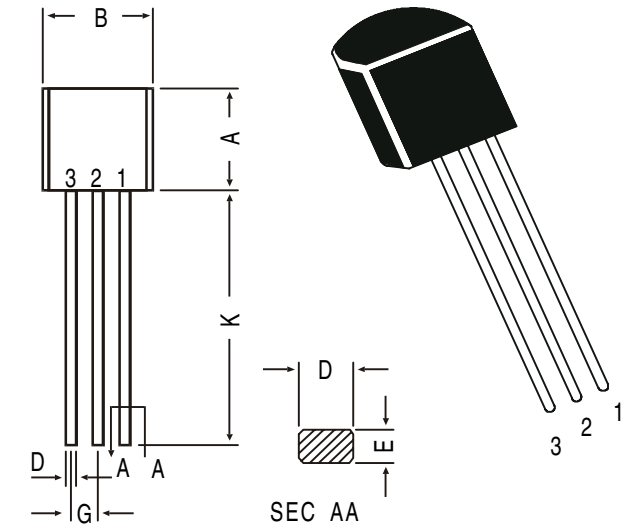
SWITCHING TIMES

Turn on time	ton	VCC=10V, IC=100mA	-	0.07	-	us
Storage time	tstg	IB1=IB2=10mA,	-	0.95	-	us
Fall time	tf	VBE(off)2=3V	-	0.07	-	us

hFE(1) * CLASSIFICATION **Y: 135-270** **G: 200-400** **L: 300-600**

*Pulse Test : PW=350us, Duty Cycle=2% Pulsed

TO-92 Plastic Package



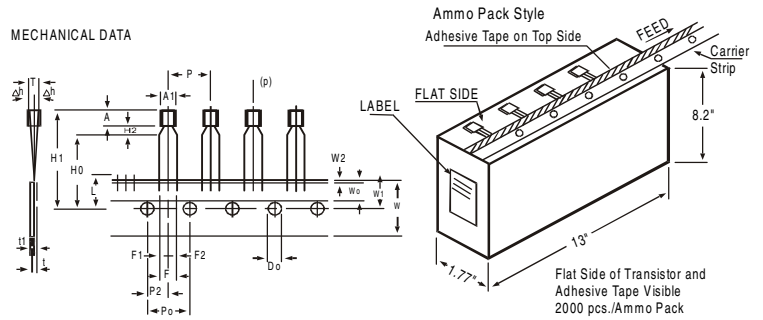
PIN CONFIGURATION

1. BASE
2. COLLECTOR
3. EMITTER

All dimensions in mm.

DIM	MIN.	MAX.
A	4.32	5.33
B	4.45	5.20
C	3.18	4.19
D	0.41	0.55
E	0.35	0.50
F	5 DEG	
G	1.14	1.40
H	1.14	1.53
K	12.70	—

TO-92 Transistors on Tape and Ammo Pack



All dimensions in mm unless specified otherwise

ITEM	SYMBOL	SPECIFICATION				REMARKS
		MIN.	NOM.	MAX.	TOL.	
BODY WIDTH	A1	4.0		4.8		
BODY HEIGHT	A	4.8		5.2		
BODY THICKNESS	T	3.9		4.2		
PITCH OF COMPONENT	P		12.7		±1	
FEED HOLE PITCH	Po		12.7		±0.3	
FEED HOLE CENTRE TO COMPONENT CENTRE	P2		6.35		±0.4	
DISTANCE BETWEEN OUTER LEADS	F		5.08		+0.6	
COMPONENT ALIGNMENT	Δh		0	1	-0.2	
TAPE WIDTH	W		18		±0.5	
HOLD-DOWN TAPE WIDTH	Wo		6		±0.2	
HOLE POSITION	W1		9		+0.7	
					-0.5	
HOLD-DOWN TAPE POSITION	W2		0.5		±0.2	
LEAD WIRE CLINCH HEIGHT	Ho		16		±0.5	
COMPONENT HEIGHT	H1		23.25			
LENGTH OF SNIPPED LEADS	L		11.0			
FEED HOLE DIAMETER	Do		4		±0.2	
TOTAL TAPE THICKNESS	t		1.2			
LEAD - TO - LEAD DISTANCE F1,	F2		2.54		+0.4	
					-0.1	
CLINCH HEIGHT	H2			3		
PULL - OUT FORCE	(P)	6N				

NOTES

1. MAXIMUM ALIGNMENT DEVIATION BETWEEN LEADS NOT TO BE GREATER THAN 0.2 mm.
2. MAXIMUM NON-CUMULATIVE VARIATION BETWEEN TAPE FEED HOLES SHALL NOT EXCEED 1 mm IN 20 PITCHES.
3. HOLDDOWN TAPE NOT TO EXCEED BEYOND THE EDGE(S) OF CARRIER TAPE AND THERE SHALL BE NO EXPOSURE OF ADHESIVE.
4. NO MORE THAN 3 CONSECUTIVE MISSING COMPONENTS ARE PERMITTED.
5. A TAPE TRAILER, HAVING AT LEAST THREE FEED HOLES ARE REQUIRED AFTER THE LAST COMPONENT.
6. SPLICES SHALL NOT INTERFERE WITH THE SPROCKET FEED HOLES.

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5.0K	17" x 15" x 13.5"	80.0K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2.0K	17" x 15" x 13.5"	32.0K	12.5 kgs

Customer Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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